

## Features

- 150 Watts peak pulse power ( $t_p = 8/20\mu s$ )
- Transient protection for high speed data lines to
- IEC 61000-4-2 (ESD)  $\pm 25kV$  (air),  $\pm 25kV$  (contact)
- IEC 61000-4-4 (EFT) 40A(5/50ns)
- Protects One Power or I/O Port
- Low leakage current
- Low operating and clamping voltages
- Solid-state silicon avalanche technology

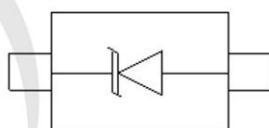
## Mechanical Characteristics

- Package: SOD-523
- Lead Finish: Matte Tin
- Case Material: "Green" Molding Compound.
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 3 per J-STD-020
- Terminal Connections: See Diagram Below
- Shipping Qty :3000pcs/7Inch Tape & Reel

## Applications

- Cellular Handsets and Accessories
- Personal Digital Assistants
- Notebooks and Handhelds
- Portable Instrumentation
- Digital Cameras
- Peripherals
- Audio Players
- Keypads, Side Keys, LCD Displays, USB2.0

## Dimensions and Pin Configuration



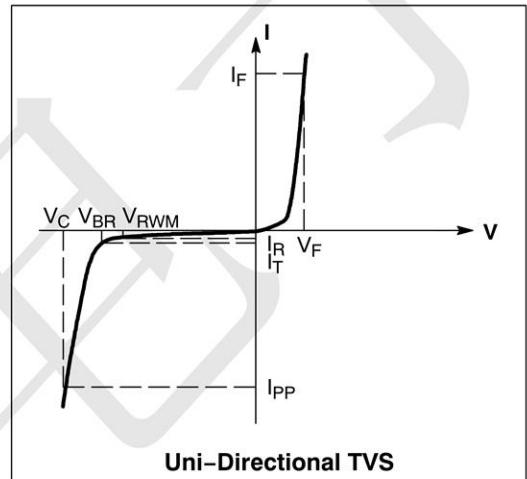
SOD-523 (Top View)

**Absolute Maximum Ratings ( $T_A=25^\circ\text{C}$  unless otherwise specified)**

Parameter	Symbol	Value	Unit
ESD per IEC 61000-4-2 (Air)	V <sub>ESD</sub>	±30	kV
ESD per IEC 61000-4-2 (Contact)		±30	
Operating Temperature Range	T <sub>J</sub>	-55 to +125	°C
Storage Temperature Range	T <sub>stg</sub>	-55 to +150	°C

**Electrical Characteristics ( $T_A=25^\circ\text{C}$  unless otherwise specified)**

Symbol	Parameter
I <sub>PP</sub>	Maximum Reverse Peak Pulse Current
V <sub>C</sub>	Clamping Voltage @ I <sub>PP</sub>
V <sub>RWM</sub>	Working Peak Reverse Voltage
I <sub>R</sub>	Maximum Reverse Leakage Current @ V <sub>RWM</sub>
V <sub>BR</sub>	Breakdown Voltage @ I <sub>T</sub>
I <sub>T</sub>	Test Current
I <sub>F</sub>	Forward Current
V <sub>F</sub>	Forward Voltage @ I <sub>F</sub>
P <sub>pk</sub>	Peak Power Dissipation
C	Capacitance @ V <sub>R</sub> = 0 and f = 1.0 MHz



Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	V <sub>RWM</sub>			12	V	
Breakdown Voltage	V <sub>BR</sub>	13.5	14.5	15	V	I <sub>T</sub> = 1mA
Reverse Leakage Current	I <sub>R</sub>			0.2	uA	V <sub>RWM</sub> = 12V
Clamping Voltage	V <sub>C</sub>			19	V	I <sub>PP</sub> = 1A (8 x 20μs pulse)
Clamping Voltage	V <sub>C</sub>			30	V	I <sub>PP</sub> = 7A (8 x 20μs pulse)
Junction Capacitance	C <sub>J</sub>		35	45	pF	VR = 0V, f = 1MHz



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ESD5Z12T1G

1-Line Uni-directional ESD Protection

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## Characteristic Curves

Fig1. 8/20 $\mu$ s Pulse Waveform

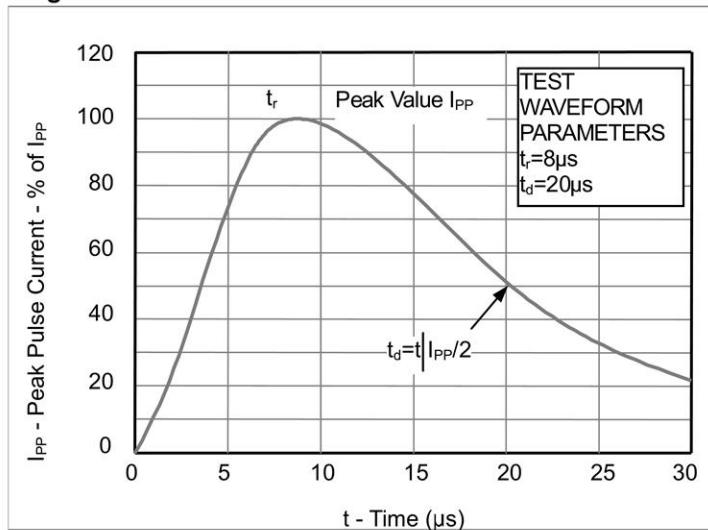


Fig2. ESD Pulse Waveform (according to IEC 61000-4-2)

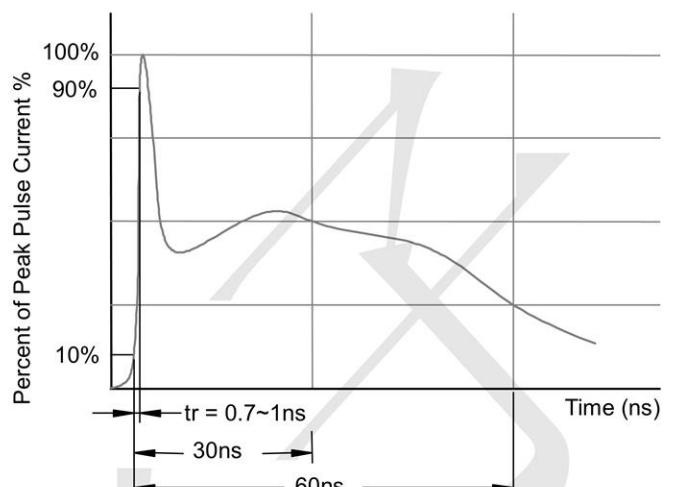
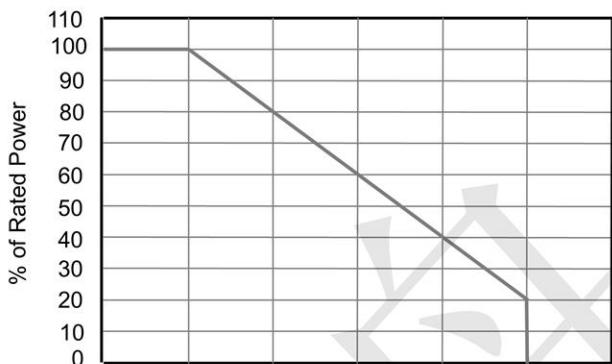


Fig3. Power Derating Curve





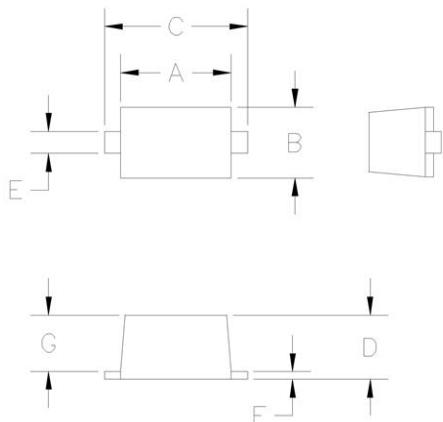
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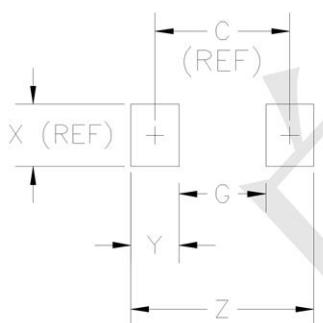
### SOD-523 Package Outline Drawing



DIM <sup>N</sup>	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	.043	.051	1.10	1.30	—
B	.028	.035	0.70	0.90	—
C	.059	.067	1.50	1.70	—
D	.020	.028	0.50	0.70	—
E	.010	.014	0.25	0.35	—
F	.004	.008	0.10	0.20	—
G	.020	.028	0.50	0.70	—

[1] CONTROLLING DIMENSION: MILLIMETERS

### Suggested Land Pattern



DIM <sup>N</sup>	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
C	—	.067	—	1.70	REF
G	—	.043	—	1.10	—
X	—	.031	—	0.80	REF
Y	—	.024	—	0.60	—
Z	—	.091	—	2.30	—

[1] CONTROLLING DIMENSION: MILLIMETERS